Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed for high volume, low cost, industrial and consumer applications such as motor control; process control; temperature, light and speed control.

- Small Size
- Passivated Die for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Available in Surface Mount Lead Form Case 369A
- Device Marking: Device Type, e.g., MCR8DCM, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open)	VDRM, VRRM		Volts
MCR8DCM MCR8DCN		600 800	
On–State RMS Current (180° Conduction Angles; T _C = 105°C)	IT(RMS)	8.0	Amps
Average On–State Current (180° Conduction Angles; T _C = 105°C)	I _{T(AV)}	5.1	Amps
Peak Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	ITSM	80	Amps
Circuit Fusing Consideration (t = 8.3 msec)	I ² t	26	A ² sec
Forward Peak Gate Power (Pulse Width ≤ 1.0 μsec, T _C = 105°C)	PGM	5.0	Watts
Forward Average Gate Power (t = 8.3 msec, T _C = 105°C)	P _G (AV)	0.5	Watts
Forward Peak Gate Current (Pulse Width ≤ 1.0 μsec, T _C = 105°C)	I _{GM}	2.0	Amps
Operating Junction Temperature Range	TJ	-40 to 125	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C

(1) VDRM, VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the device are exceeded.



ON Semiconductor

http://onsemi.com

SCRs 8 AMPERES RMS 600 thru 800 VOLTS





D-PAK CASE 369A STYLE 4

PIN ASSIGNMENT			
1 Cathode			
2	Anode		
3	Gate		
4	Anode		

ORDERING INFORMATION

Device	Package	Shipping
MCR8DCMT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)
MCR8DCNT4	DPAK 369A	16mm Tape and Reel (2.5K/Reel)

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance — Junction to Case — Junction to Ambient — Junction to Ambient ⁽¹⁾	R _θ JC R _θ JA R _θ JA	2.2 88 80	°C/W
Maximum Lead Temperature for Soldering Purposes(2)	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			
Peak Repetitive Forward or Peak Repetitive Reverse Blocking Current (V_{AK} = Rated V_{DRM} or V_{RRM} , Gate Open) $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _{DRM} , IRRM		_	0.01 5.0	mA
ON CHARACTERISTICS					
Peak On–State Voltage(3) (I _{TM} = 16 A)	V _{TM}	_	1.4	1.8	Volts
Gate Trigger Current (Continuous dc) ($V_{AK} = 12 \text{ V}, R_L = 100 \Omega, T_J = 25^{\circ}\text{C}$) ($T_J = -40^{\circ}\text{C}$)	^I GT	2.0	7.0 —	15 30	mA
Gate Trigger Voltage (Continuous dc) $ (V_{AK} = 12 \text{ V}, \text{ R}_{L} = 100 \Omega, \text{ T}_{J} = 25^{\circ}\text{C}) \\ (T_{J} = -40^{\circ}\text{C}) \\ (T_{J} = 125^{\circ}\text{C}) $	VGT	0.5 — 0.2	0.65 — —	1.0 2.0 —	Volts
Holding Current ($V_{AK} = 12 \text{ V}$, Initiating Current = 200 mA, Gate Open) $T_{J} = 25^{\circ}\text{C}$ $T_{J} = -40^{\circ}\text{C}$	lн	4.0	22 —	30 60	mA
Latching Current $(V_{AK} = 12 \text{ V}, I_G = 15 \text{ mA}, T_J = 25^{\circ}\text{C})$ $(V_{AK} = 12 \text{ V}, I_G = 30 \text{ mA}, T_J = -40^{\circ}\text{C})$	ΙL	4.0	22 —	30 60	mA
DYNAMIC CHARACTERISTICS			•		
Critical Rate of Rise of Off–State Voltage (VAK = Rated VDRM, Exponential Waveform, Gate Open, TJ = 125°C)	dv/dt	50	200	_	V/μs

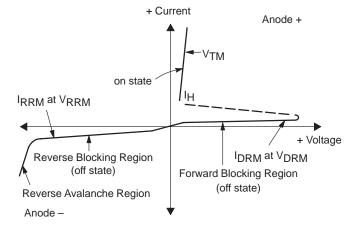
⁽¹⁾ Surface mounted on minimum recommended pad size.

^{(2) 1/8&}quot; from case for 10 seconds.

⁽³⁾ Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter
VDRM	Peak Repetitive Off State Forward Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V_{TM}	Peak On State Voltage
Ιн	Holding Current



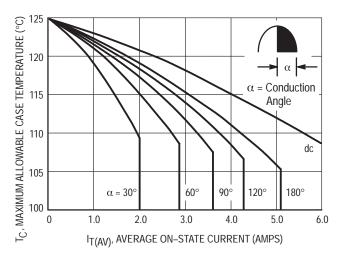


Figure 1. Average Current Derating

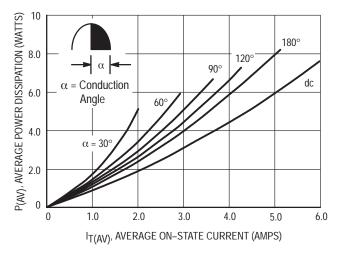


Figure 2. On-State Power Dissipation

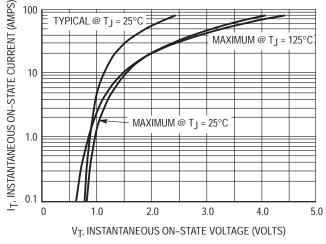


Figure 3. On-State Characteristics

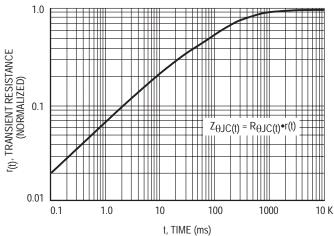


Figure 4. Transient Thermal Response

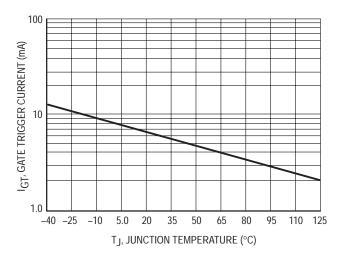


Figure 5. Typical Gate Trigger Current versus Junction Temperature

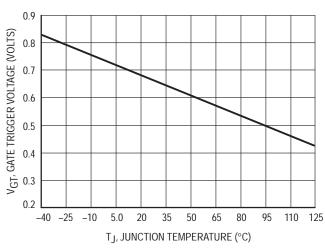


Figure 6. Typical Gate Trigger Voltage versus
Junction Temperature

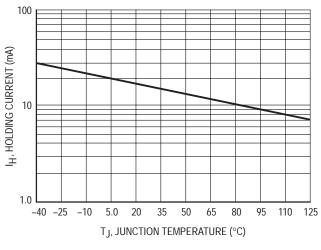


Figure 7. Typical Holding Current versus Junction Temperature

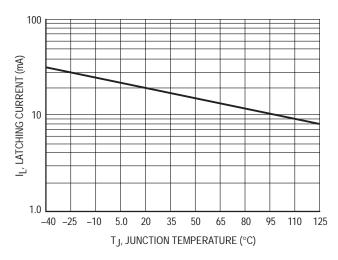


Figure 8. Typical Latching Current versus Junction Temperature

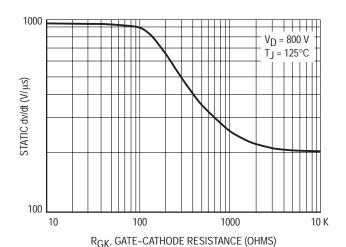
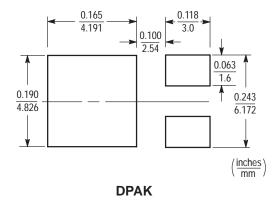


Figure 9. Exponential Static dv/dt versus Gate–Cathode Resistance

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

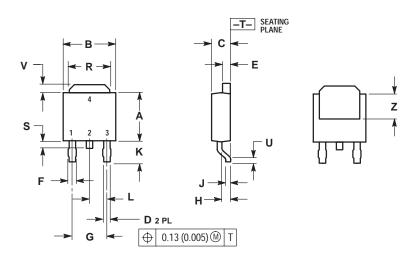
Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



PACKAGE DIMENSIONS

D-PAK CASE 369A-13 ISSUE Z



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

	INC	INCHES MILLIMETERS		IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Ε	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020		0.51	
V	0.030	0.050	0.77	1.27
Z	0.138		3.51	

STYLE 4: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE



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